NSN 5961-00-435-3754

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-435-3754 **Inclosure Material:** Glass and metal **Overall Length:** 0.765 inches **Overall Diameter:** 0.221 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case Semiconductor Material: Silicon **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 70.0 degrees celsius ambient air **Terminal Type And Quantity:** 1 ferrule and 1 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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